	Search Text	DBs	Time Stamp
1	driver near3 circuit	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/24 17:22
2	buffer near3 circuit	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/24 17:22
3	source near3 follower	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/24 17:23
4	tft or (thin adj film adj transistor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/24 17:32
5	analog near3 memory	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/24 17:23
6	S1 same S2	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/24 17:23
7	S6 same S3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/24 17:23
8	S5 same S7	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/24 17:25
9	S1 and S2	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/24 17:25
10	S9 and S3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/24 17:25
11	S4 and S10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/24 17:25
12	S5 and S11	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/24 17:25
13	S4 and S12	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/24 17:32
14	S4 same channel	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/24 17:38
15	channel near7 (polycrystal$ or polysilicon)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/24 17:33

	Search Text	DBs	Time Stamp
16	depletion near3 mode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/24 17:33
17	S15 same S4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/24 17:33
18	S16 same S17	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/24 17:34
19	S14 same S15	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/24 17:39
20	S16 same S19	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/24 17:39
21	S16 and S19	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/24 17:51
22	257/402	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/24 17:53
23	257/248	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/24 18:00
24	257/348	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/24 18:00
25	S15 and S24	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/24 18:01
26	S25 and depletion	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/24 18:02
27	S25 and S16	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/24 18:02
28	source near3 follower	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 14:01
29	polycrystal$ or polysilicon	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 14:02
30	tft or (thin adj film adj transistor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 14:03

	Search Text	DBs	Time Stamp
31	depletion adj mode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 14:03
32	S28 and S31	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 14:03
33	S29 and S32	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 14:03
34	S33 and S30	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 14:09
35	S30 and S32	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 14:09
36	S35 not S34	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 14:10
37	S32 and S29	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 15:15
38	"6225866"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 15:17
39	"6313819"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 15:50
40	shift adj register	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 16:00
41	buffer adj circuit	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 15:51
42	source adj follower	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 15:51
43	analog adj memory	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 15:51
44	S40 and S41 and S42 and S43	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 15:56
45	bootstrap adj circuit	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 15:59

	Search Text	DBs	Time Stamp
46	S40 and S41 and S42 and S43 and S45	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 15:56
47	S40 and S41 and S43 and S45	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 15:59
48	S40 same S41 same S43	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 16:02
49	S40 and S41 and S43	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 16:10
50	S49 and (bootstrap)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 16:44
51	S49 and S28	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 16:16
52	S40 and S45	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 16:16
53	S41 and S52	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 16:28
54	S30 and S54	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 16:28
55	S31 and S45	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 16:44
56	bootstrap and S31	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 16:44
57	low adj power	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 16:44
58	S56 and S57	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 16:49
59	S31 same S45	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 16:45
60	S57 and S59	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 16:45

	Search Text	DBs	Time Stamp
61	S40 and S58	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 17:59
62	"5949271"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 17:59
63	S31 and S62	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/06/25 17:59